Not recommended for new designs. No replacement is available

Data Sheet PD No. 60255 revA

International
IOR Rectifier

IRS21851SPbF

SINGLE HIGH SIDE DRIVER IC

Features

- Gate drive supply range from 10 V to 20 V
- Undervoltage lockout for V_{BS} and V_{CC}
- 3.3 V and 5 V input logic compatible
- Tolerant to negative transient voltage
- Matched propagation delays for all channels
- RoHS compliant

Description

The IRS21851 is a high voltage, high speed power MOSFET and IGBT single high-side driver with propagation delay matched output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The floating logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic and can be operated up to 600 V above the ground. The output driver features a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side configuration, which operates up to 600 V.

Product Summary

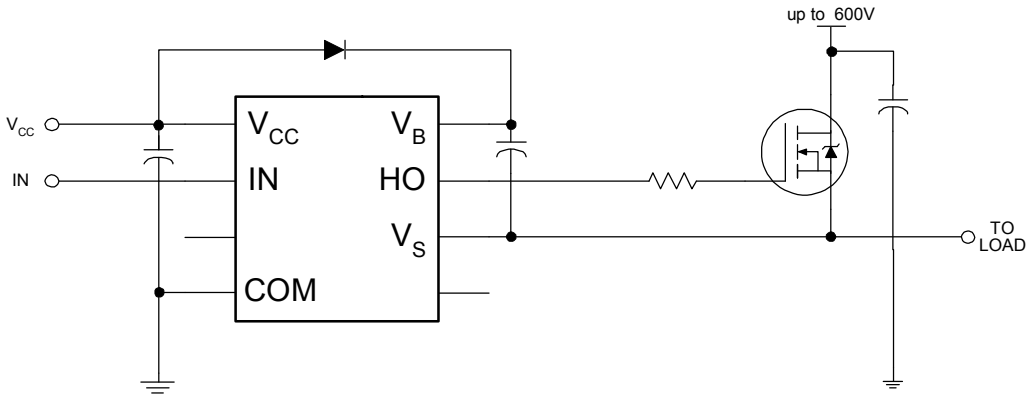
V_{OFFSET}	600 V max.
I_O+/-	4 A / 4 A
V_{OUT}	10 V - 20 V
$t_{on/off}$ (typ.)	160 ns & 160 ns

Package



8-Lead SOIC
IRS21851

Typical Connection



(Refer to Lead Assignments for correct pin configuration). This diagram shows electrical connections only.
Please refer to our Application Notes and DesignTips for proper circuit board layout.

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Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units
V_{CC}	Low-side supply voltage	-0.3	20 (Note 1)	V
V_{IN}	Logic input voltage (HIN)	COM -0.3	V_{CC} + 0.3	
V_B	High-side floating well supply voltage	-0.3	620 (Note 1)	
V_S	High-side floating well supply return voltage	V_B - 20	V_B + 0.3	
V_{HO}	Floating gate drive output voltage	V_S - 0.3	V_B + 0.3	
dV_s/dt	Allowable V_S offset supply transient relative to COM	—	50	V/ns
P_D	Package power dissipation @ $T_A \leq +25$ °C	—	1.25	W
Rth_{JA}	Thermal resistance, junction to ambient	—	100	°C/W
T_J	Junction temperature	-55	150	°C
T_S	Storage temperature	-55	150	
T_L	Lead temperature (soldering, 10 seconds)	—	300	

Note 1: All supplies are fully tested at 25 V. An internal 20 V clamp exists for each supply.

Recommended Operating Conditions

For proper operation, the device should be used within the recommended conditions. All voltage parameters are absolute voltages referenced to COM. The offset rating are tested with supplies of (V_{CC}-COM)=(V_B-V_S)=15 V.

Symbol	Definition	Min.	Max.	Units
V_{CC}	Low-side supply voltage	10	20	V
V_{IN}	HIN input voltage	COM	V_{CC}	
V_B	High-side floating well supply voltage	V_S + 10	V_S + 20	
V_S	High-side floating well supply offset voltage	Note 2	600	
V_{HO}	Floating gate drive output voltage	V_S	V_B	
T_A	Ambient temperature	-40	125	°C

Note 2: Logic operational for V_S of -5 V to 600 V. Logic state held for V_S of -5 V to -V_{BS}. (Please refer to the Design Tip DT97-3 for more details).

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Dynamic Electrical Characteristics

(V_{CC}-COM)=(V_B-V_S)=15 V, T_A = 25 °C. C_L = 1000 pF unless otherwise specified. All parameters are referenced to COM.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
t_{on}	Turn-on propagation delay	—	160	210	ns	(V_S -COM) = 0 V
t_{off}	Turn-off propagation delay	—	160	210		(V_S -COM) = 600 V
t_r	Turn-on rise time	—	15	40		
t_f	Turn-off fall time	—	15	40		

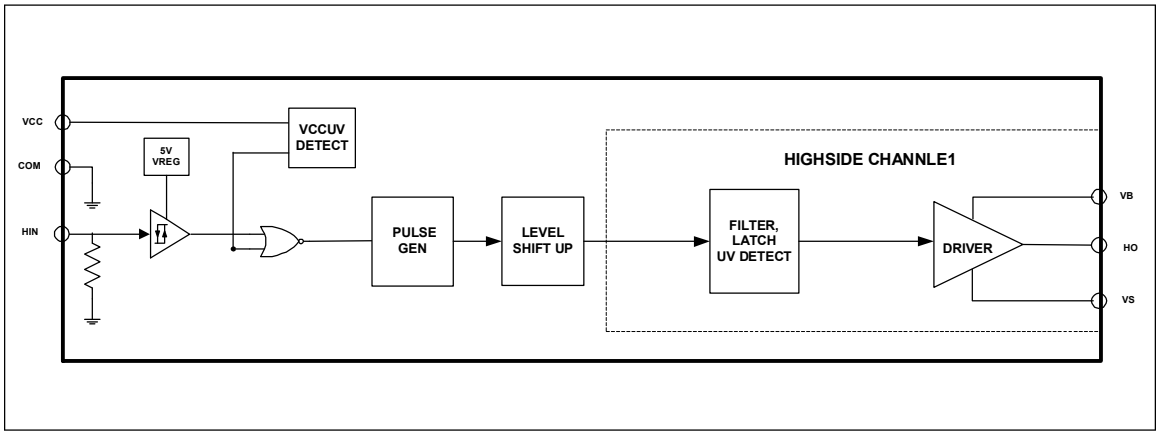
Static Electrical Characteristics

(V_{CC}-COM)=(V_B-V_S)=15 V. The V_{IN}, $V_{TH,}$ and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced respective V_S and are applicale to the respective output leads HO. The V_{CC} parameters are referenced to COM. The V_{BSUV} parameters are referenced to V_S.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
V_{CCUV+}	V_{CC} supply undervoltage positive going threshold	8.0	8.9	9.8	V	
V_{CCUV-}	V_{CC} supply undervoltage negative going threshold	7.4	8.2	9.0		
V_{BSUV+}	V_{BS} supply undervoltage positive going threshold	8.0	8.9	9.8		
V_{BSUV-}	V_{BS} supply undervoltage negative going threshold	7.4	8.2	9.0		
I_{LK}	High-side floating well offset supply leakage current	—	—	50	µA	V_B = V_S = 600 V
I_{QBS}	Quiescent V_{BS} supply current	—	80	150		HIN = 0 V or 5 V
I_{QCC}	Quiescent V_{CC} supply current	—	120	240		
V_{IH}	Logic “1” input voltage	2.5	—	—	V	
V_{IL}	Logic “0” input voltage	—	—	0.8		
$V_{OH,\ HO}$	HO high level output voltage, V_{BIAS} - V_O	—	20	60	mV	I_O = 2 mA
$V_{OL,\ HO}$	HO low level output voltage, V_O	—	10	30		
I_{IN+}	Logic “1” input bias current	—	10	20	µA	V_{HIN} = 5 V
I_{IN-}	Logic “0” input bias current	—	0	5		V_{HIN} = 0 V
$I_{O+,\ HO}$	Output high short circuit pulsed current HO	—	4	—	A	V_O = 0 V, V_{IN} = 0 V PW ≤ 10 µs
$I_{O-,\ HO}$	Output low short circuit pulsed current HO	—	4	—		V_O = 15 V, V_{IN} = 15 V PW ≤ 10 µs

Not recommended for new designs. No replacement is available

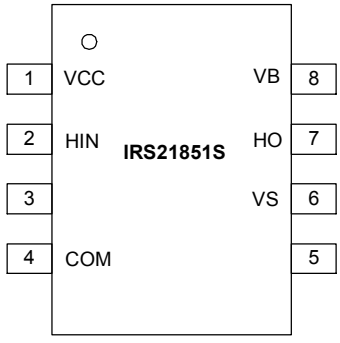
Functional Block Diagram



Lead Definitions

Symbol	Description
V_{CC}	Low-side supply voltage
COM	Ground
V_B	High-side drive floating supply
HO	High-side driver outputs
V_S	High voltage floating supply return
HIN	Logic inputs for high-side gate driver output (in phase)

Lead Assignments



8-Lead SOIC

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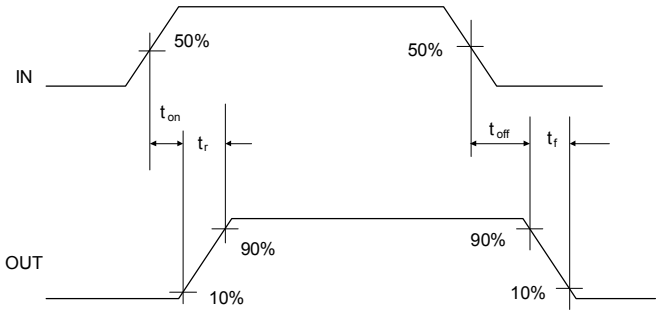


Figure 1. Switching Time Waveforms

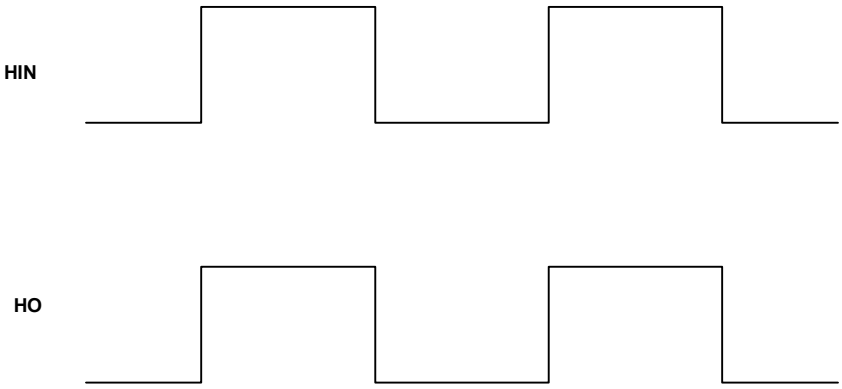


Figure 2. Input/Output Timing Diagram

Not recommended for new designs. No replacement is available

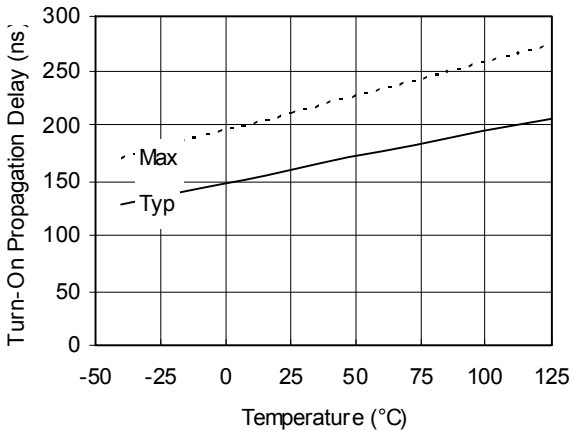


Figure 3A. Turn-On Propagation Delay vs. Temperature

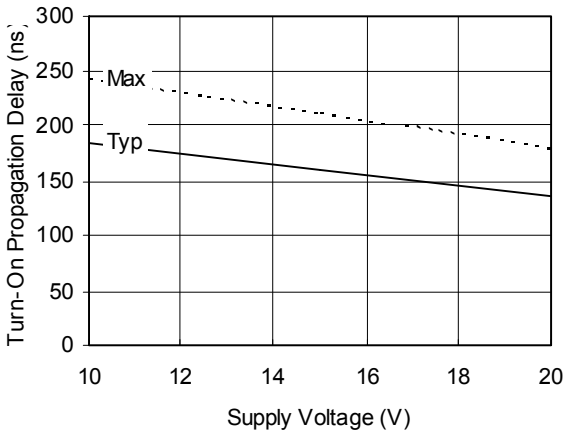


Figure 3B. Turn-On Propagation Delay vs. Supply Voltage

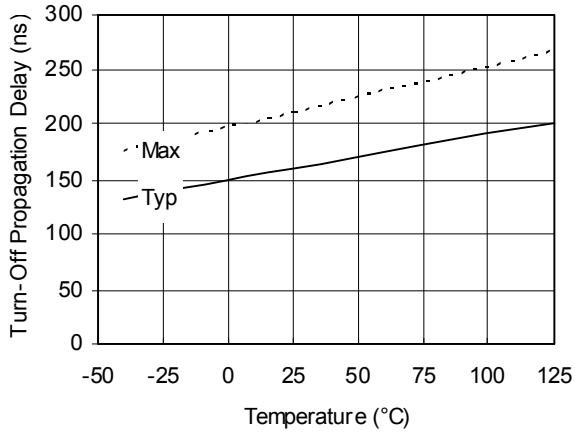


Figure 4A. Turn-Off Propagation Delay vs. Temperature

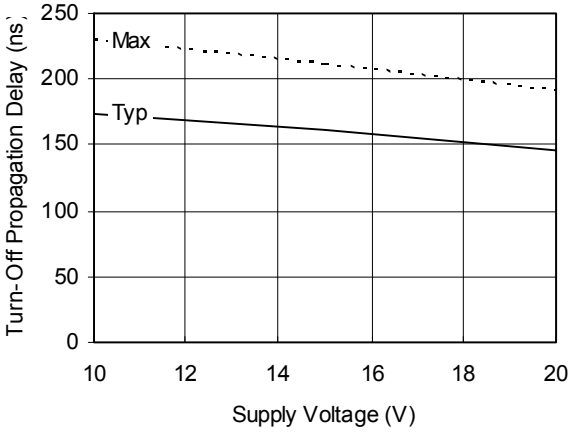


Figure 4B. Turn-Off Propagation Delay vs. Supply Voltage

Not recommended for new designs. No replacement is available

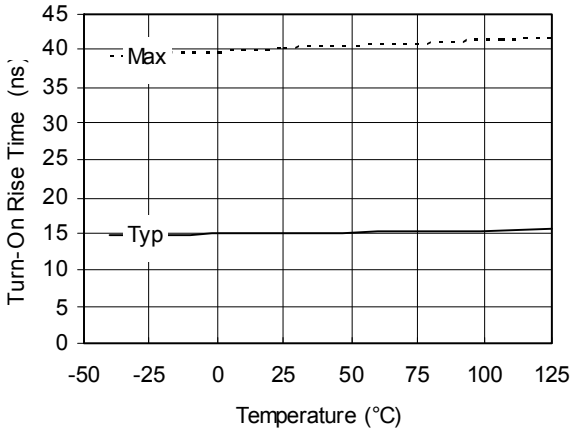


Figure 5A. Turn-On Rise Time vs. Temperature

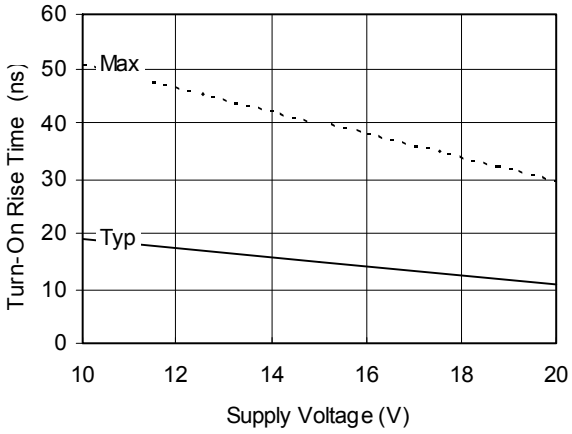


Figure 5B. Turn-On Rise Time vs. Supply Voltage

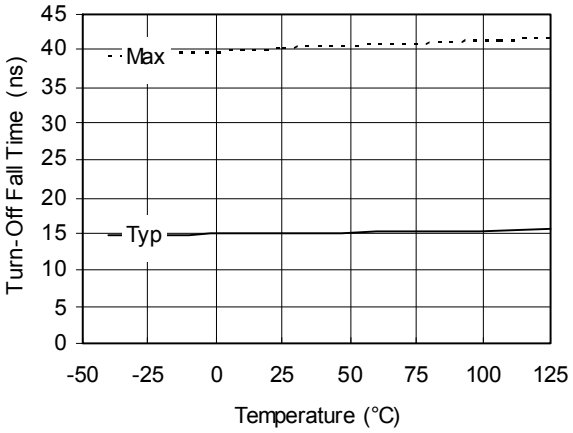


Figure 6A. Turn-Off Fall Time vs. Temperature

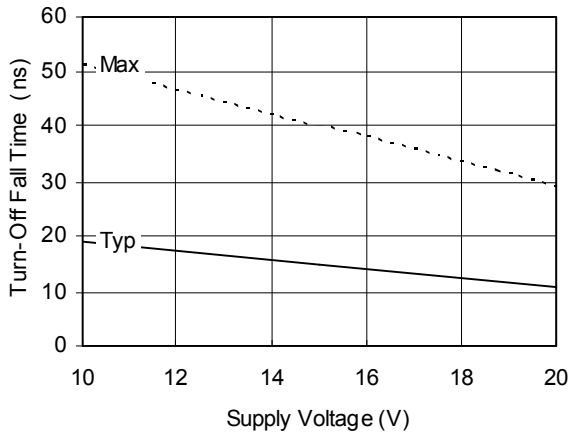


Figure 6B. Turn-Off Fall Time vs. Supply Voltage

Not recommended for new designs. No replacement is available

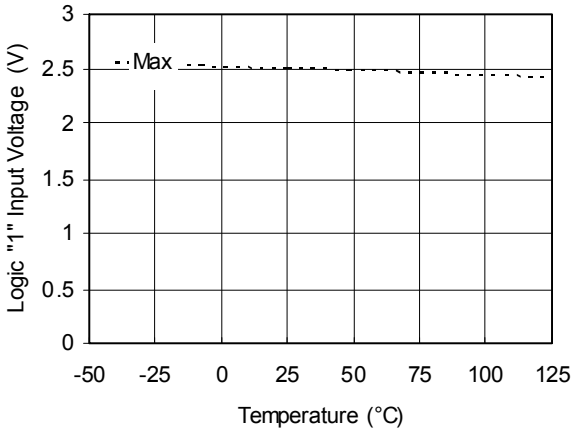


Figure 7A. Logic "1" Input Voltage vs. Temperature

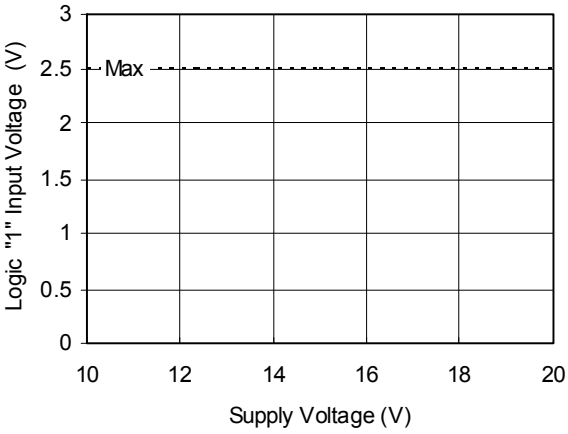


Figure 7B. Logic "1" Input Voltage vs. Supply Voltage

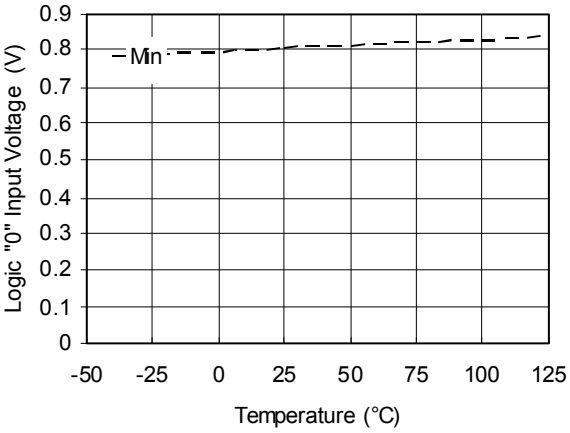


Figure 8A. Logic "0" Input Voltage vs. Temperature

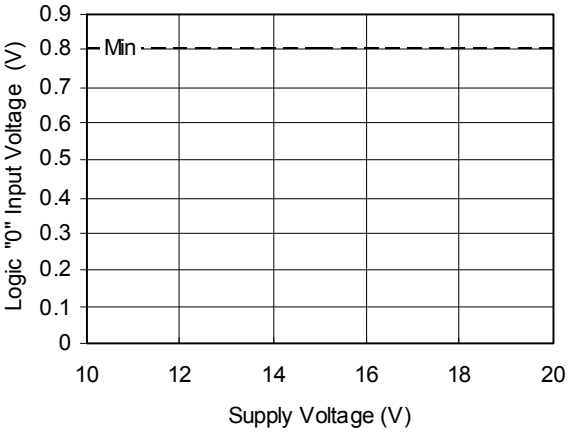


Figure 8B. Logic "0" Input Voltage vs. Supply Voltage

Not recommended for new designs. No replacement is available

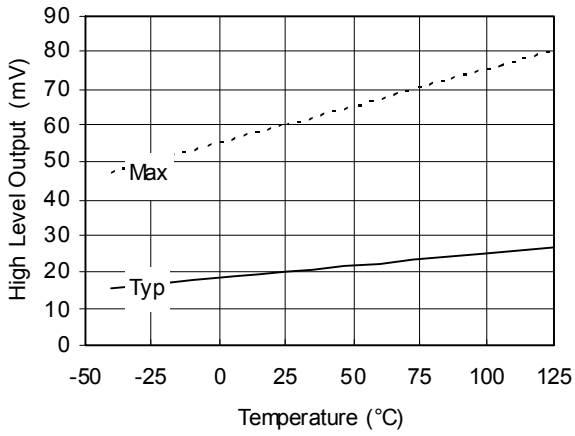


Figure 9A. High Level Output vs. Temperature (I_O = 2 mA)

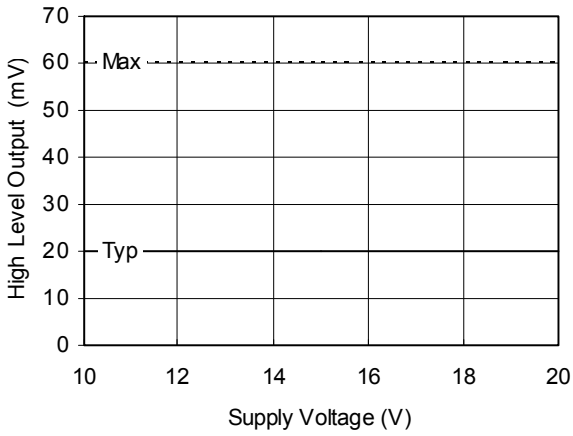


Figure 9B. High Level Output vs. Supply Voltage (I_O =2 mA)

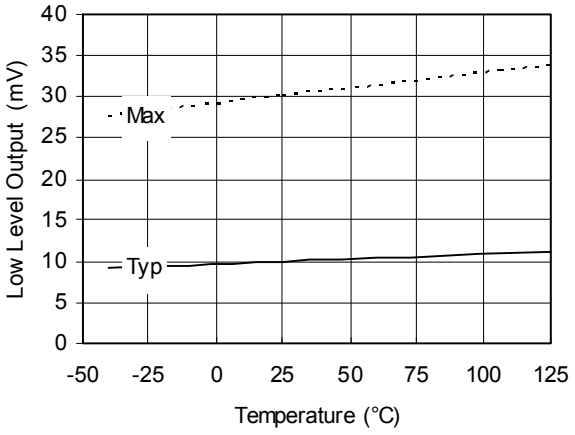


Figure 10A. Low Level Output vs. Temperature (I_O=2 mA)

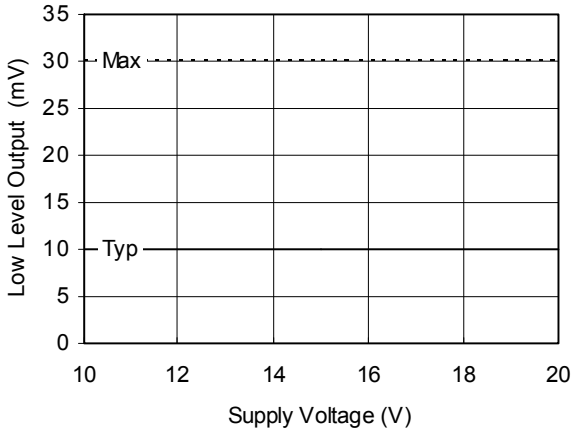


Figure 10B. Low Level Output vs. Supply Voltage (I_O=2 mA)

Not recommended for new designs. No replacement is available

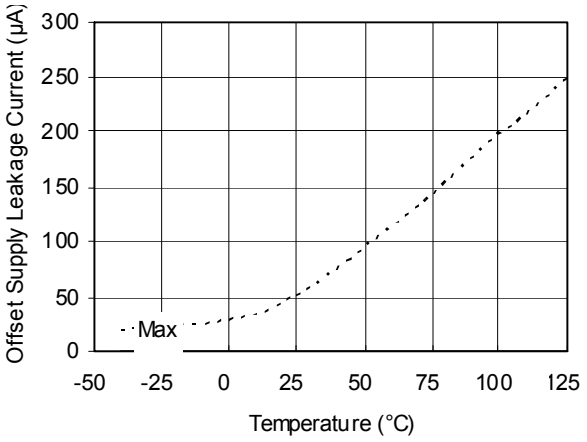


Figure 11A. Offset Supply Leakage Current vs. Temperature

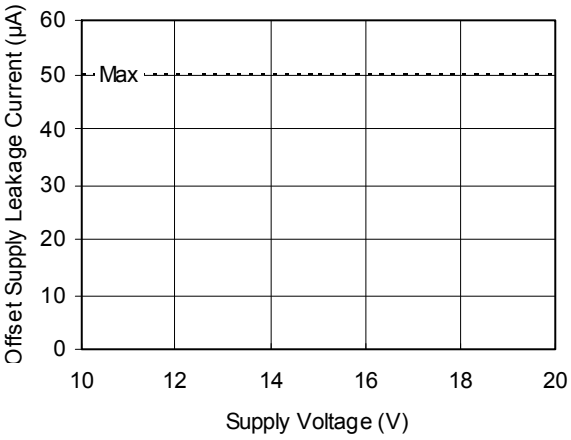


Figure 11B. Offset Supply Leakage Current vs. Supply Voltage

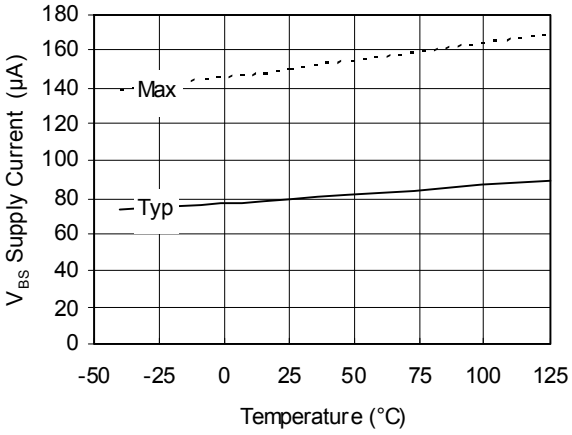


Figure 12A. V_{BS} Supply Current vs. Temperature

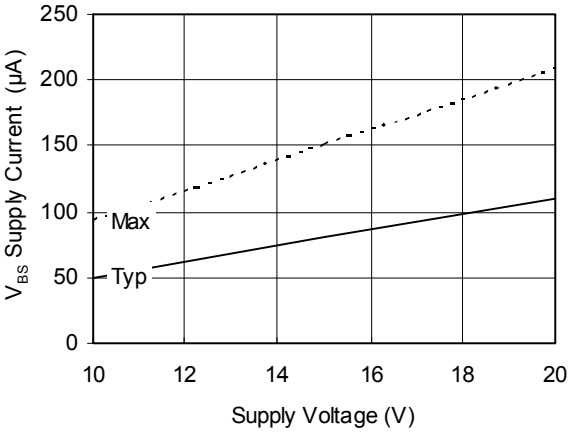


Figure 12B. V_{BS} Supply Current vs. Supply Voltage

Not recommended for new designs. No replacement is available

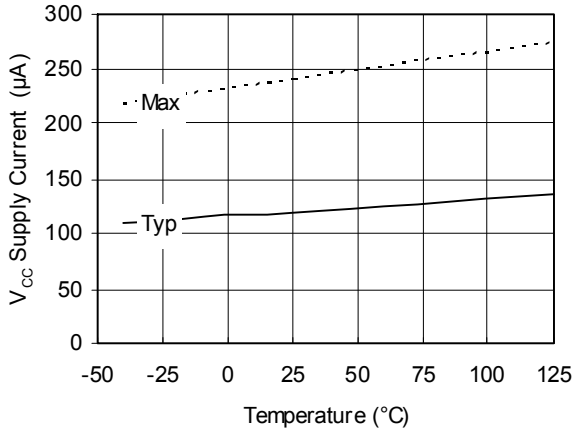


Figure 13A. V_{CC} Supply Current vs. Temperature

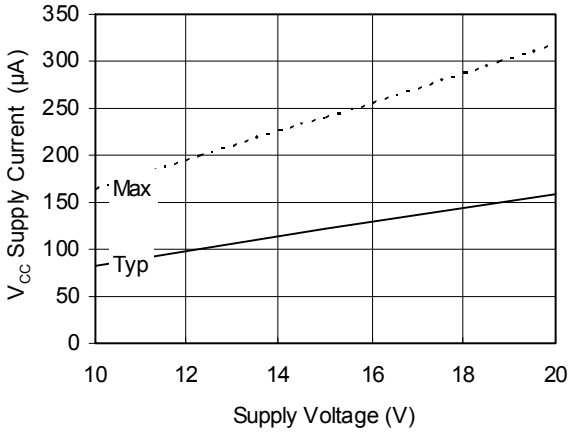


Figure 13B. V_{CC} Supply Current vs. Supply Voltage

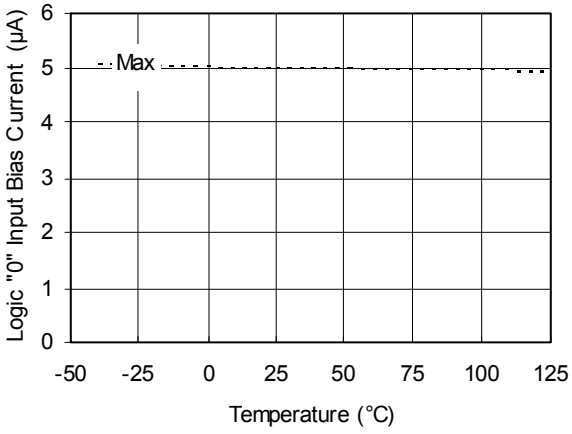


Figure 14A. Logic "0" Input Bias Current vs. Temperature

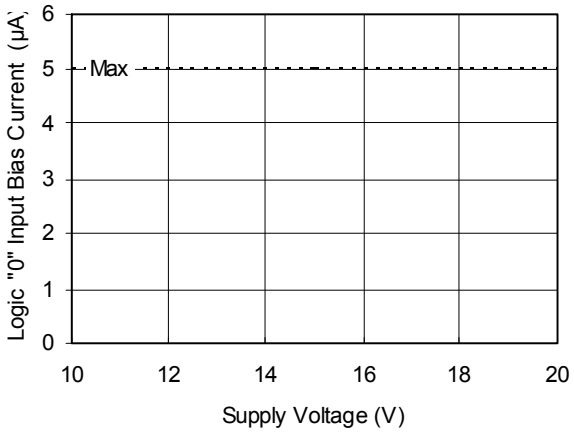


Figure 14B. Logic "0" Input Bias Current vs. Supply Voltage

Not recommended for new designs. No replacement is available

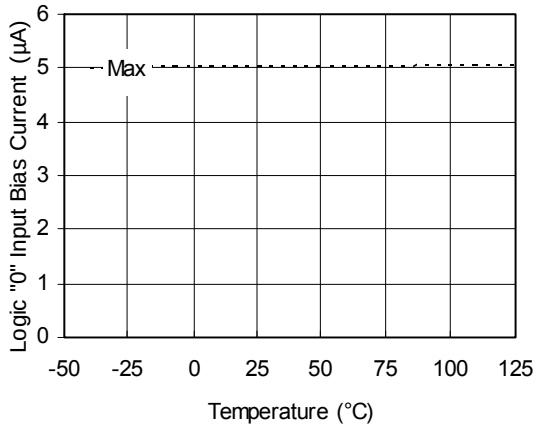


Figure 15A. Logic "0" Input Bias Current vs. Temperature

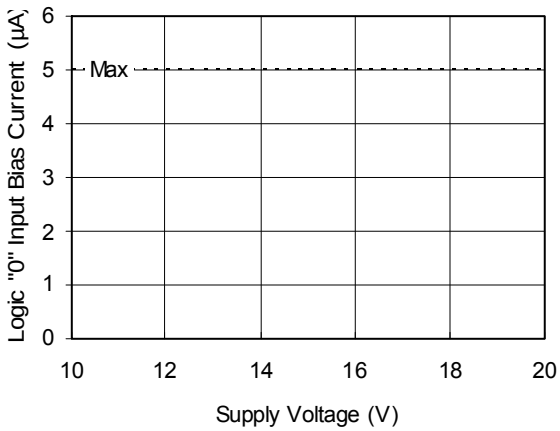


Figure 15B. Logic "0" Input Bias Current vs. Voltage

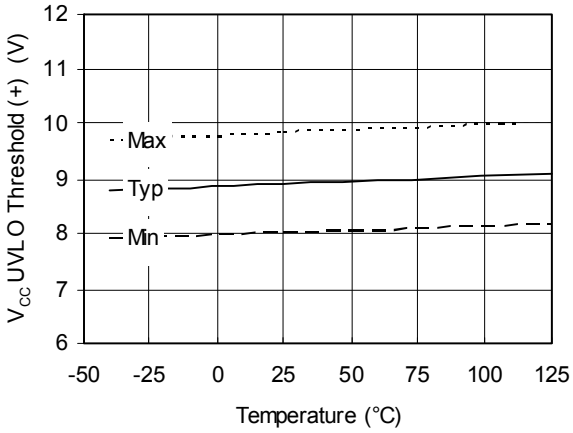


Figure 16. V_{cc} Undervoltage Threshold (+) vs. Temperature

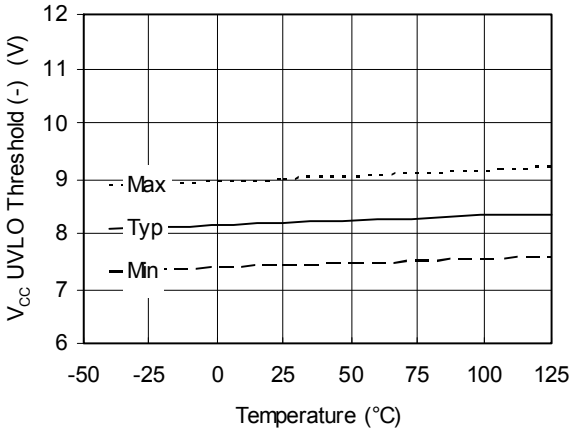


Figure 17. V_{cc} Undervoltage Threshold (-) vs. Temperature

Not recommended for new designs. No replacement is available

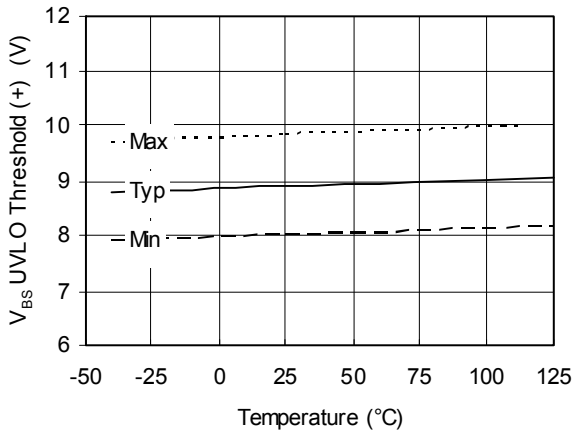


Figure 18. V_{BS} Undervoltage Threshold (+) vs. Temperature

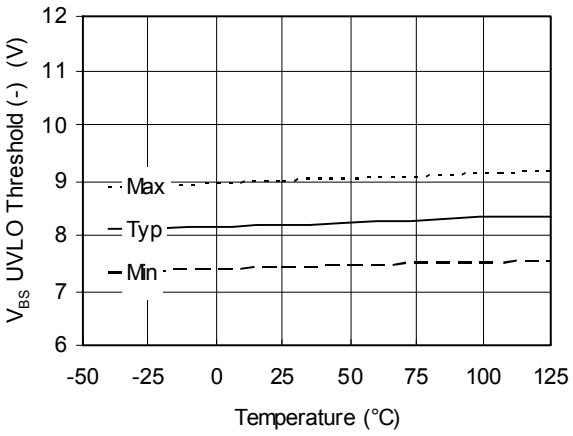


Figure 19. V_{BS} Undervoltage Threshold (-) vs. Temperature

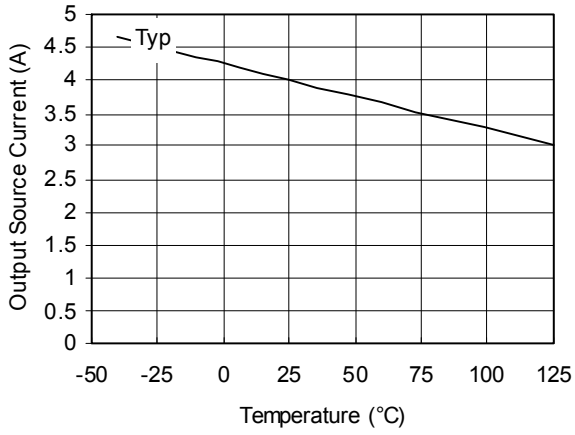


Figure 20A. Output Source Current vs. Temperature

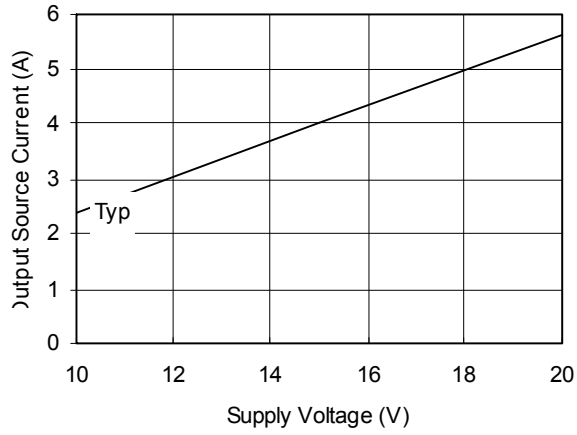


Figure 20B. Output Source Current vs. Supply Voltage

Not recommended for new designs. No replacement is available

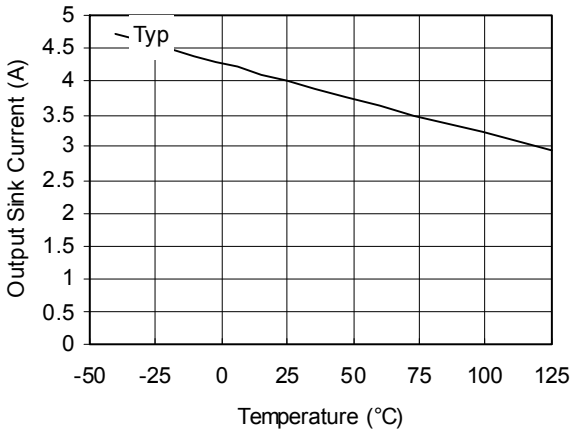


Figure 21A. Output Sink Current vs. Temperature

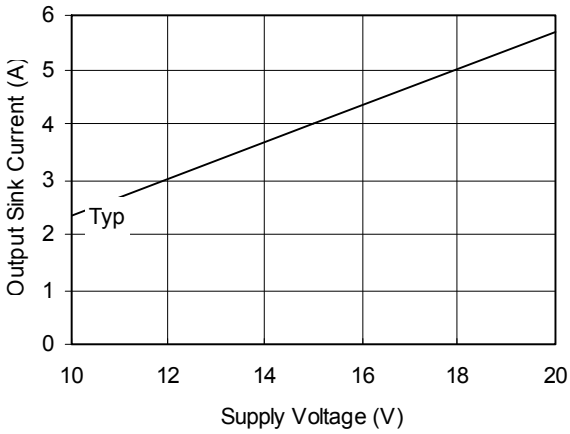
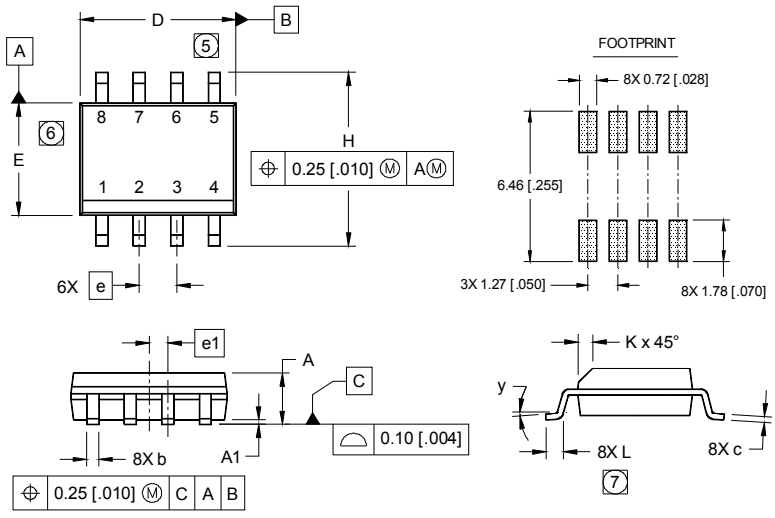


Figure 21B. Output Sink Current vs. Supply Voltage

Case outline



DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.0532	.0688	1.35	1.75
A1	.0040	.0098	0.10	0.25
b	.013	.020	0.33	0.51
c	.0075	.0098	0.19	0.25
D	.189	.1968	4.80	5.00
E	.1497	.1574	3.80	4.00
e	.050 BASIC		1.27 BASIC	
e 1	.025 BASIC		0.635 BASIC	
H	.2284	.2440	5.80	6.20
K	.0099	.0196	0.25	0.50
L	.016	.050	0.40	1.27
y	0°	8°	0°	8°

NOTES:
1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.

5 DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 [.006].

6 DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 [.010].

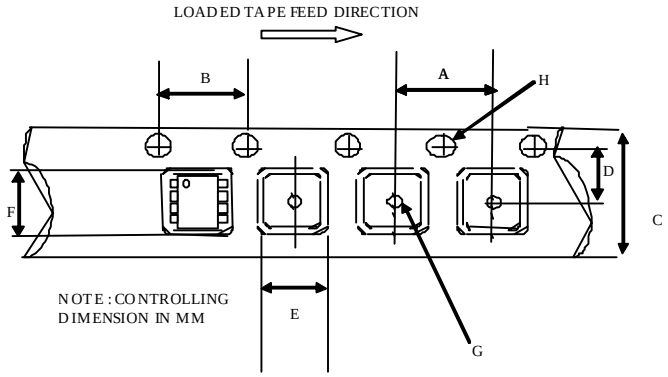
7 DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.

01-6027

8-Lead SOIC

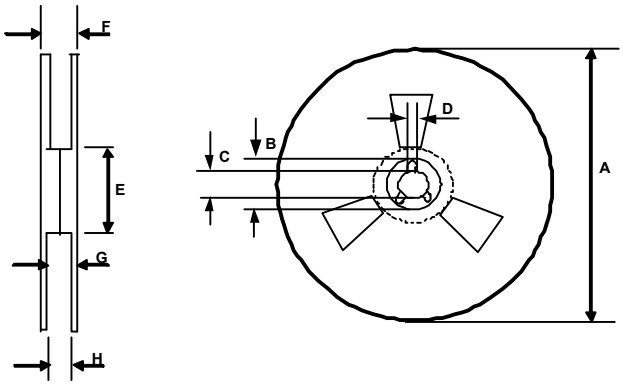
Not recommended for new designs. No replacement is available

Tape & Reel
8-lead SOIC



CARRIER TAPE DIMENSION FOR 8SOICN

	Metric		Imperial	
Code	Min	Max	Min	Max
A	7.90	8.10	0.311	0.318
B	3.90	4.10	0.153	0.161
C	11.70	12.30	0.46	0.484
D	5.45	5.55	0.214	0.218
E	6.30	6.50	0.248	0.255
F	5.10	5.30	0.200	0.208
G	1.50	n/a	0.059	n/a
H	1.50	1.60	0.059	0.062

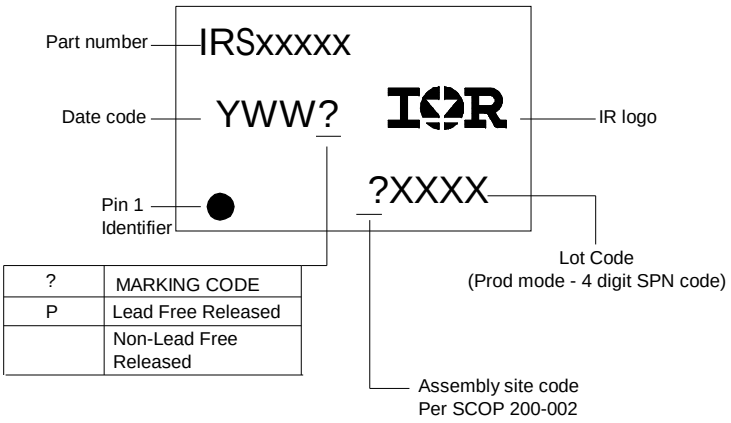


REEL DIMENSIONS FOR 8SOICN

	Metric		Imperial	
Code	Min	Max	Min	Max
A	329.60	330.25	12.976	13.001
B	20.95	21.45	0.824	0.844
C	12.80	13.20	0.503	0.519
D	1.95	2.45	0.767	0.096
E	98.00	102.00	3.858	4.015
F	n/a	18.40	n/a	0.724
G	14.50	17.10	0.570	0.673
H	12.40	14.40	0.488	0.566

Not recommended for new designs. No replacement is available

LEADFREE PART MARKING INFORMATION



?	MARKING CODE
P	Lead Free Released
	Non-Lead Free Released

ORDER INFORMATION

8-Lead SOIC order IRS21851SPbF
8-Lead SOIC Tape & Reel IRS21851STRPbF

Rev.	Date	Page #	Description of Change
A	6/10/80	1	"Not Recommended for new design: Please use IRS21850D"
		1	ton/toff values should read 160ns not 170ns

The SOIC-8 is MSL2 qualified.
This product has been designed and qualified for the industrial level.
Qualification standards can be found at www.irf.com
IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245 Tel: (310) 252-7105
Data and specifications subject to change without notice. 6/10/2008